



A Product Line of Diodes Incorporated



DXT458P5

NPN SILICON PLANAR HIGH VOLTAGE TRANSISTOR PowerDI[®]5

Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 2.8W
- $V_{CEO} = 400V$
- Ic = 300mA; I_{CM} = 1A
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data Case: PowerDI[®]5

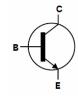
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 🚳
- Weight: 0.093 grams (approximate)

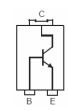
Applications

- PSU start up switch
- Telecom switch









Top View

Bottom View

Device Schematic

Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging	
DXT458P5-13	PowerDI [®] 5	5000/Tape & Reel	

Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



DXT458 = Product Type Marking Code DII = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	400	V
Collector-Emitter Voltage	V _{CEO}	400	V
Emitter-Base Voltage	V _{EBO}	5	V
Continuous Collector Current	Ic	300	mA
Base Current	IB	200	mA
Peak Pulse Current	I _{CM}	1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 4)	PD	2.8	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T _A = 25°C	$R_{\theta JA}$	45	°C/W
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 5)	PD	1.3	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T _A = 25°C	$R_{ extsf{ heta}JA}$	96	°C/W
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 6)	PD	0.7	W
Thermal Resistance, Junction to Ambient Air (Note 6) @T _A = 25°C	$R_{\theta JA}$	179	°C/W
Thermal Resistance, Junction to Collector Terminal	$R_{\theta JT}$	14	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

4. Device mounted on 1.6mm FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm. Notes:

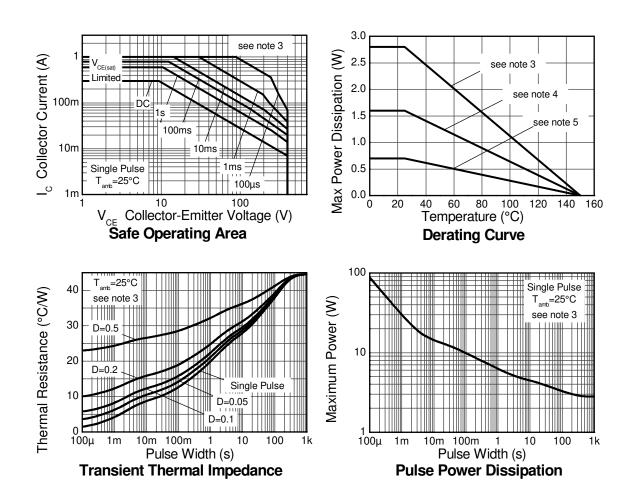
Device mounted on 1.6mm FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
Device mounted on 1.6mm FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.



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Electrical Characteristics @T_A = 25°C unless otherwise specified

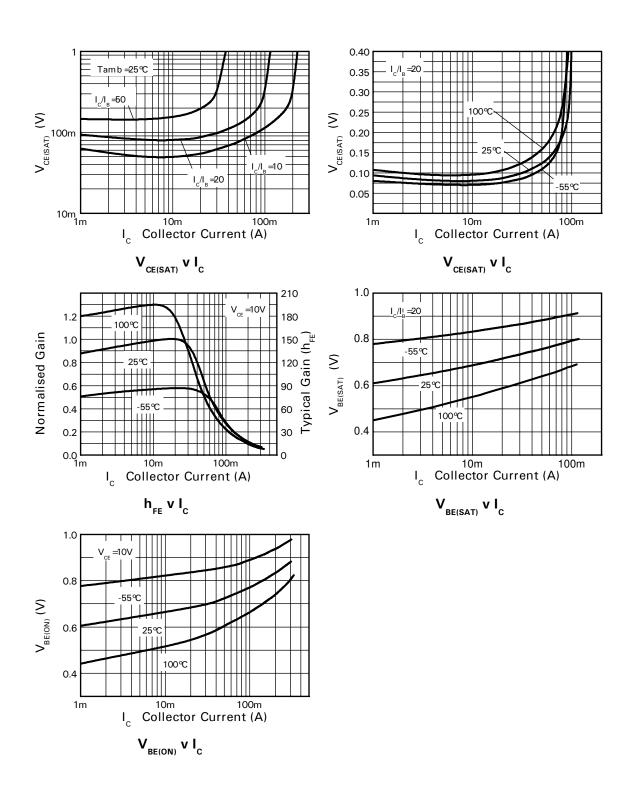
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	400	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 7)	V _{CEO(sus)}	400	-	_	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5	-	-	V	$I_E = 100 \mu A$
Collector Cutoff Current	I _{CBO}	-	-	100	nA	V _{CB} = 320V
Collector Cutoff Current	I _{CES}	-	-	100	nA	V _{CB} = 320V
Emitter Cutoff Current	I _{EBO}	-	-	100	nA	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	-	-	200	mV	$I_C = 20mA$, $I_B = 2mA$
		-		500	IIIV	$I_C = 50 \text{mA}, I_B = 6 \text{mA}$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	-	-	900	mV	$I_C = 50mA$, $I_B = 5mA$
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	-	-	900	mV	$V_{CE} = 10V, I_{C} = 50mA$
		100	-	-		$V_{CE} = 10V, I_{C} = 1mA$
DC Current Gain (Note 7)	h _{FE}	100	-	300	-	$V_{CE} = 10V, I_{C} = 50mA$
		15	-	_		$V_{CE} = 10V, I_{C} = 100mA$
Transition Frequency	fт	50	_		MHz	$V_{CE} = 20V, I_C = 10mA,$
		50				f = 20MHz
Output Capacitance	C _{obo}	-	-	5	pF	$V_{CB} = 20V$, f = 1MHz
Switching Times	t _{on} t _{off}	- 13	135 –	_	ns	$V_{CC} = 100V, I_C = 50mA,$
		-	2260			$I_{B1} = 5mA, I_{B2} = 10mA$

7. Pulse Test: Pulse width \leq 300µs. Duty cycle \leq 2.0%. Notes:





Typical Characteristic

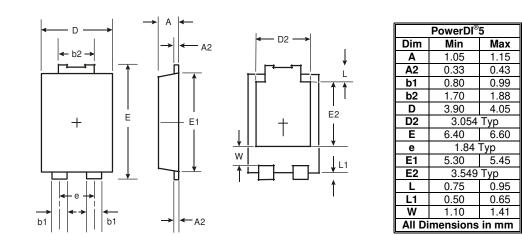


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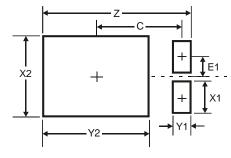




Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
E1	0.9





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